

1. General description

Hyperfast power diode in a SOD142 (2-lead TO247) plastic package.

2. Features and benefits

- Fast switching and soft reverse recovery characteristics
- Low forward voltage drop
- Low leakage current
- Low reverse recovery current
- Reduces switching losses in associated MOSFET or IGBT

3. Applications

- UPS
- EV Charger
- Welding Machine
- Air Conditioner

4. Quick reference data

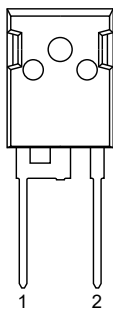
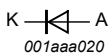
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $T_{mb} \leq 56$ °C; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3	-	-	75	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25$ μ s; $T_{mb} \leq 56$ °C; square-wave pulse	-	-	150	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse; Fig. 4	-	-	700	A
		$t_p = 8.3$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse; Fig. 4	-	-	750	A
Static characteristics						
V_F	forward voltage	$I_F = 75$ A; $T_j = 25$ °C; Fig. 6	-	2.2	2.75	V
		$I_F = 75$ A; $T_j = 150$ °C; Fig. 6	-	1.6	2.1	V
Dynamic characteristics						
t_{rr}	reverse recovery time	$I_F = 1$ A; $V_R = 30$ V; $di_F/dt = 50$ A/ μ s; $T_j = 25$ °C; Fig. 7	-	-	50	ns

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
		$I_F = 75\text{ A}; V_R = 400\text{ V}; di_F/dt = 200\text{ A}/\mu\text{s}; T_j = 25\text{ }^\circ\text{C}; \text{Fig. 7}$	-	42	-	ns
		$I_F = 75\text{ A}; V_R = 400\text{ V}; di_F/dt = 200\text{ A}/\mu\text{s}; T_j = 125\text{ }^\circ\text{C}; \text{Fig. 7}$	-	106	-	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 <p style="text-align: center;">TO-247 (SOD142)</p>	 <p style="text-align: center;">001aaa020</p>
2	A	anode		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BYC75W-600P	TO-247	Plastic Single-ended through-hole package; Heatsink mounted; 1 mounting hole; 2-lead TO-247	SOD142

7. Marking

Table 4. Marking codes

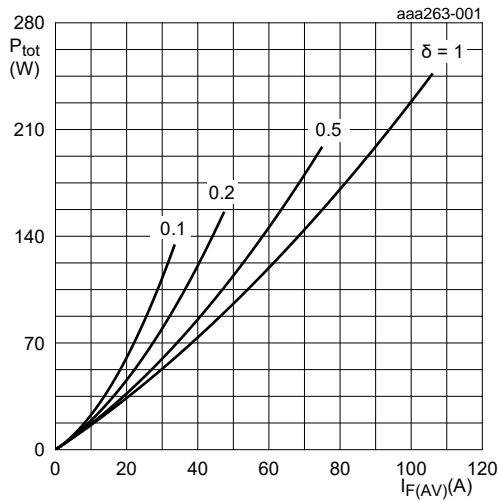
Type number	Marking code
BYC75W-600P	BYC75W-600P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

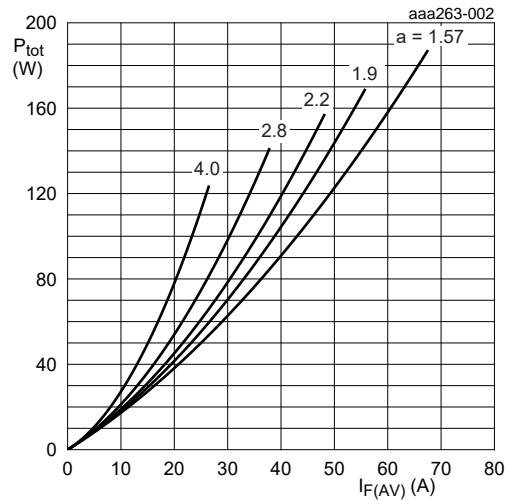
Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	$\delta = 0.5$; T _{mb} ≤ 56 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	75	A
I _{FRM}	repetitive peak forward current	$\delta = 0.5$; t _p = 25 μs; T _{mb} ≤ 56 °C; square-wave pulse	-	150	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; Fig. 4	-	700	A
		t _p = 8.3 ms; T _{j(init)} = 25 °C; sine-wave pulse; Fig. 4	-	750	A
T _{stg}	storage temperature		-55	175	°C
T _j	junction temperature		-	175	°C



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 1.547 \text{ V}; R_s = 0.007 \text{ } \Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

$$V_o = 1.547 \text{ V}; R_s = 0.007 \text{ } \Omega$$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

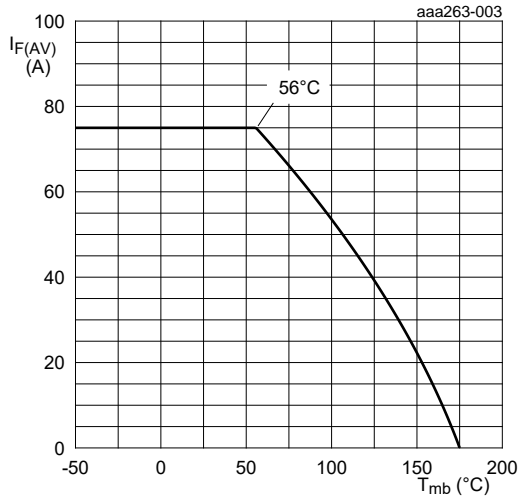


Fig. 3. Forward current as a function of mounting base temperature; maximum values

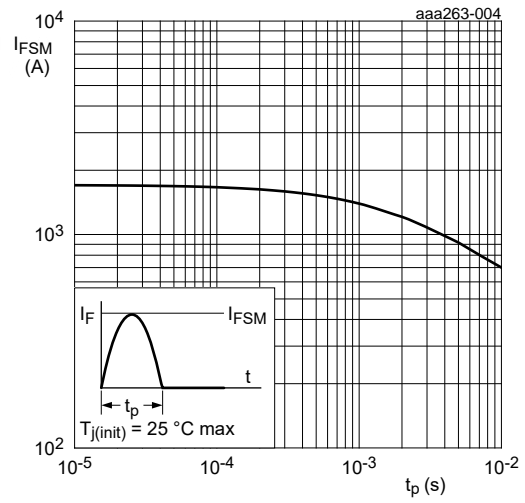


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	full cycles; Fig. 5	-	-	0.6	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W

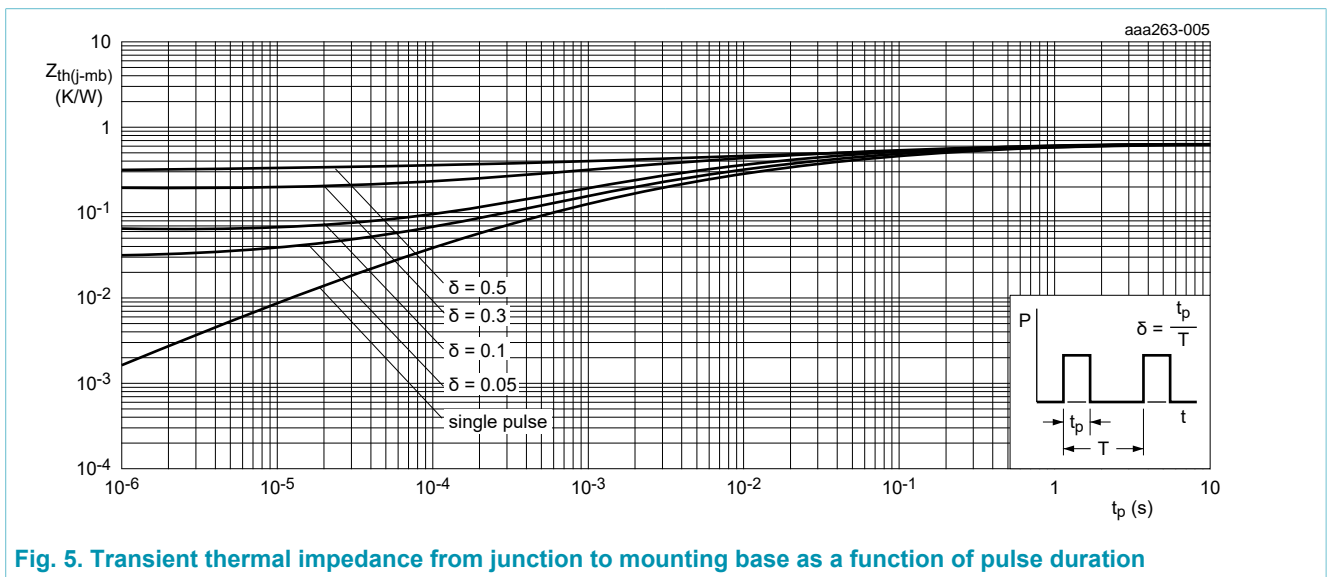
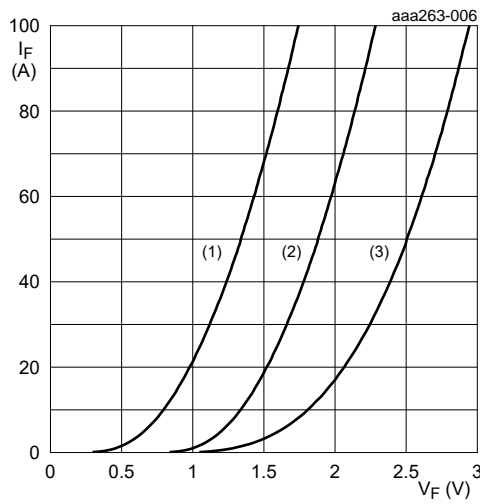


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _F	forward voltage	I _F = 75 A; T _j = 25 °C; Fig. 6	-	2.2	2.75	V
		I _F = 75 A; T _j = 150 °C; Fig. 6	-	1.6	2.1	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	10	μA
		V _R = 600 V; T _j = 125 °C	-	-	1	mA
Dynamic characteristics						
Q _r	recovered charge	I _F = 75 A; V _R = 400 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7	-	85	-	nC
		I _F = 75 A; V _R = 400 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7	-	640	-	nC
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C; Fig. 7	-	-	50	ns
		I _F = 75 A; V _R = 400 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7	-	42	-	ns
		I _F = 75 A; V _R = 400 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7	-	106	-	ns
I _{RM}	peak reverse recovery current	I _F = 75 A; V _R = 400 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7	-	4.1	-	A
		I _F = 60 A; V _R = 200 V; dI _F /dt = 200 A/μs; T _j = 125 °C; Fig. 7	-	12.2	-	A



V₀ = 1.547 V; R_s = 0.007 Ω
 (1) T_j = 150 °C; typical values
 (2) T_j = 150 °C; maximum values
 (3) T_j = 25 °C; maximum values

Fig. 6. Forward current as a function of forward voltage

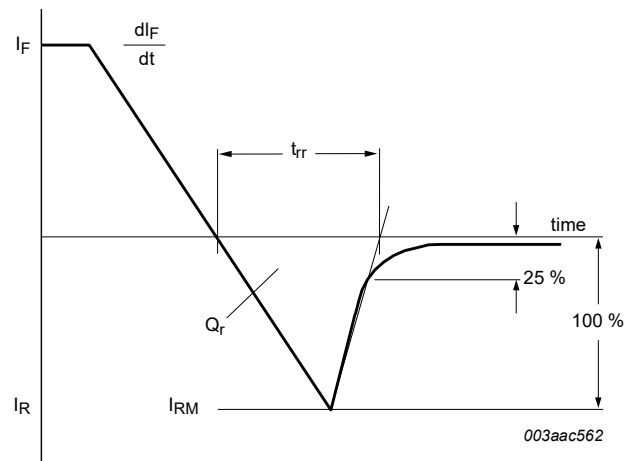
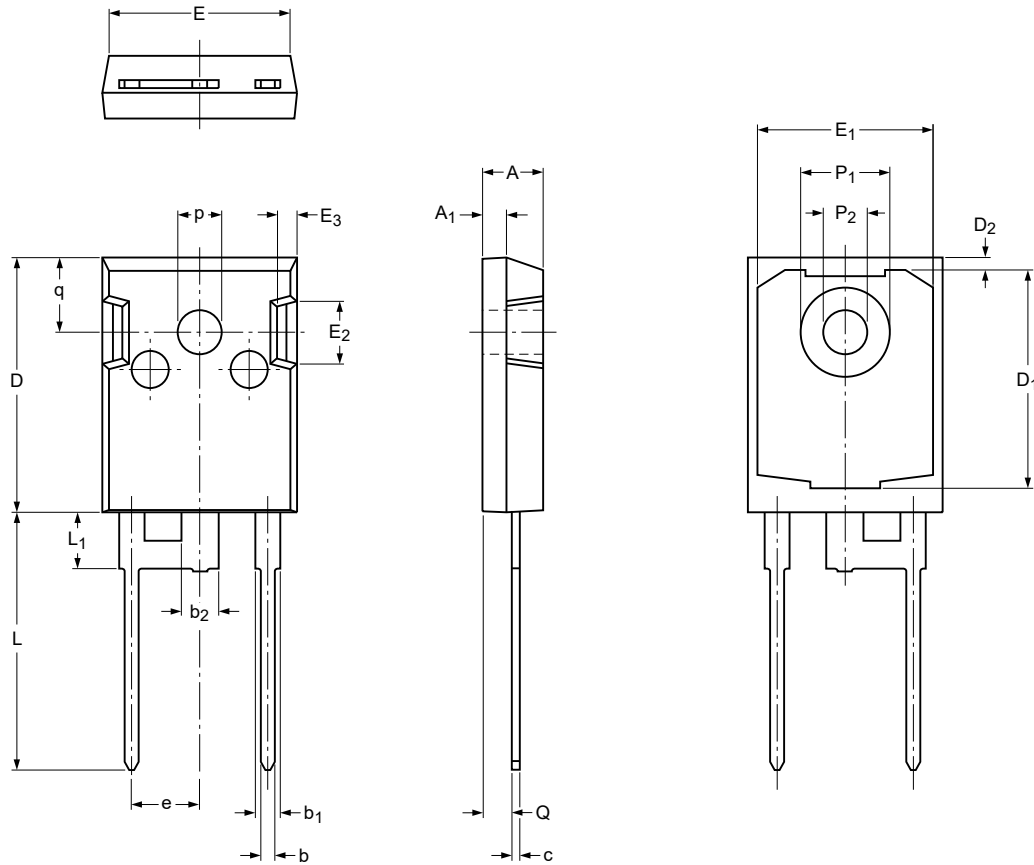


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline

Plastic Single-ended through-hole package; Heatsink mounted; 1 mounting hole; 2-lead TO-247 SOD142



Dimensions (mm are the original dimensions)

Unit	A	A ₁	b	b ₁	b ₂	c	D	D ₁	D ₂	e	E	E ₁	E ₂	E ₃	L	L ₁	p	p ₁	p ₂	q	Q
max	5.2	2.1	1.4	2.2	3.2	0.7	20.6	17.68	1.2	15.75	14.22	5.2	1.8	20.9	4.75	3.7	7.3	3.6	6.18	2.6	
nom										5.45											
min	4.7	1.9	1.0	1.8	2.8	0.5	20.3	17.28	0.8	15.45	13.82	4.8	1.4	20.4	4.25	3.5	7.1	3.4	5.78	2.2	

sod142_po

Outline version	References			European projection	Issue date
	IEC	JEDEC	JEITA		
SOD142		TO247			-12-11-13- 12-11-27

Fig. 8. Package outline TO-247 (SOD142)

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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